

M1FK60

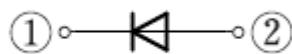
**Fast Recovery Diodes
600V, 1A**

Feature

- Small SMD
- High Voltage
- High Recovery Speed
- Available for automotive use
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): M1F
Package (JEDEC Code): DO-219AA similar

**Equivalent circuit****Absolute Maximum Ratings** (unless otherwise specified : $T_I=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T_{STG}		-55 to 150	°C
Junction temperature	T_J		-55 to 150	°C
Repetitive peak reverse voltage	V_{RRM}		600	V
Average forward current	$I_F(AV)$	50Hz sine wave, Resistance load, $T_I=116^\circ\text{C}$	1	A
Average forward current	$I_F(AV)$	50Hz sine wave, Resistance load, On alumina substrate, $T_a=25^\circ\text{C}$ *	0.77	A
Average forward current	$I_F(AV)$	50Hz sine wave, Resistance load, On glass-epoxy substrate, $T_a=25^\circ\text{C}$ *	0.51	A
Surge forward current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle, Peak value, $T_j=25^\circ\text{C}$	15	A
Surge forward current	I_{FSM1}	$t_p=1\text{ms}$, Sine wave, Non-repetitive, Peak value, $T_j=25^\circ\text{C}$	35	A

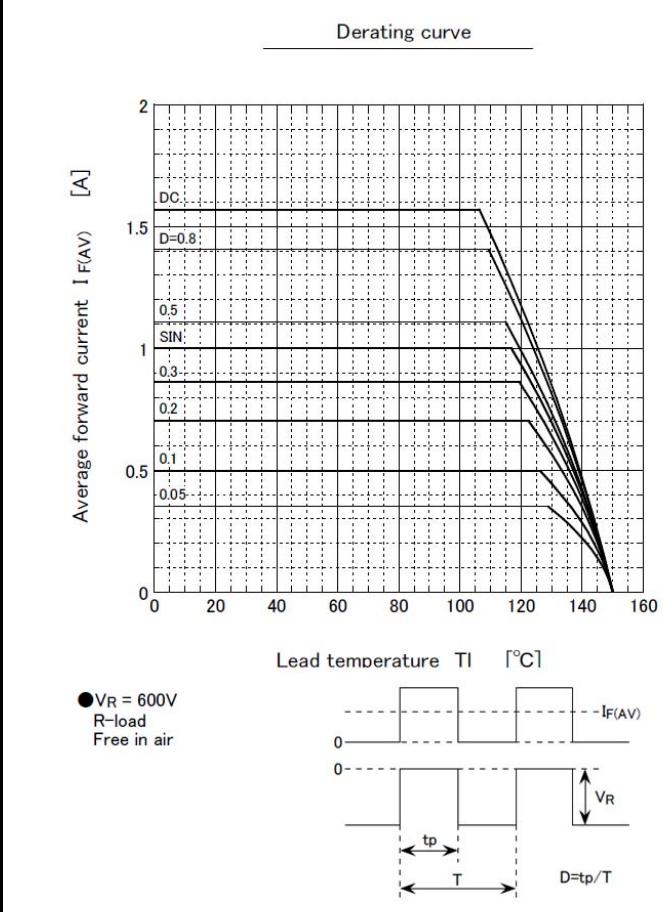
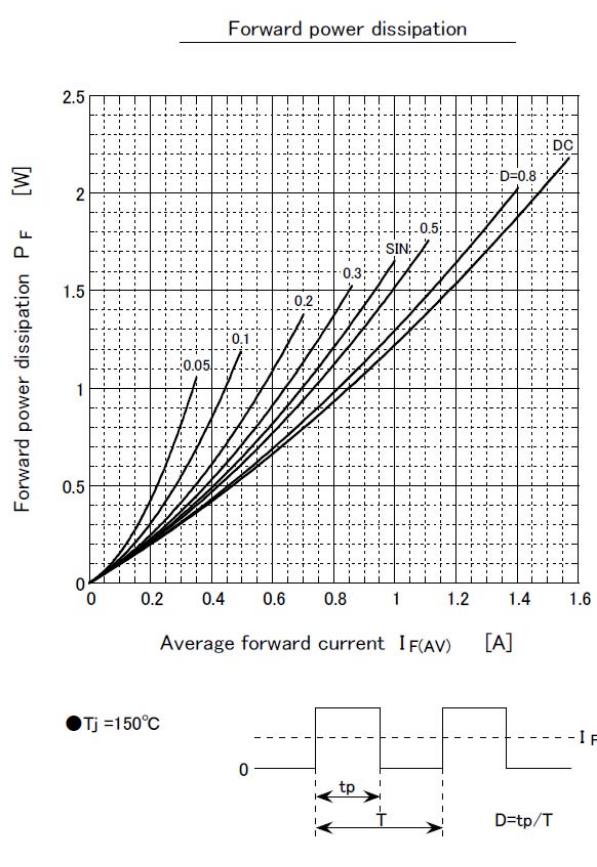
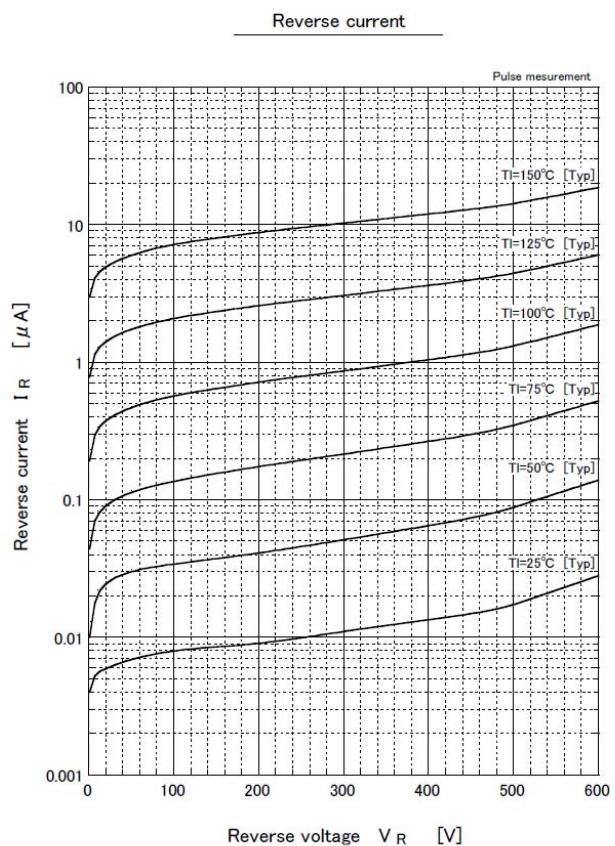
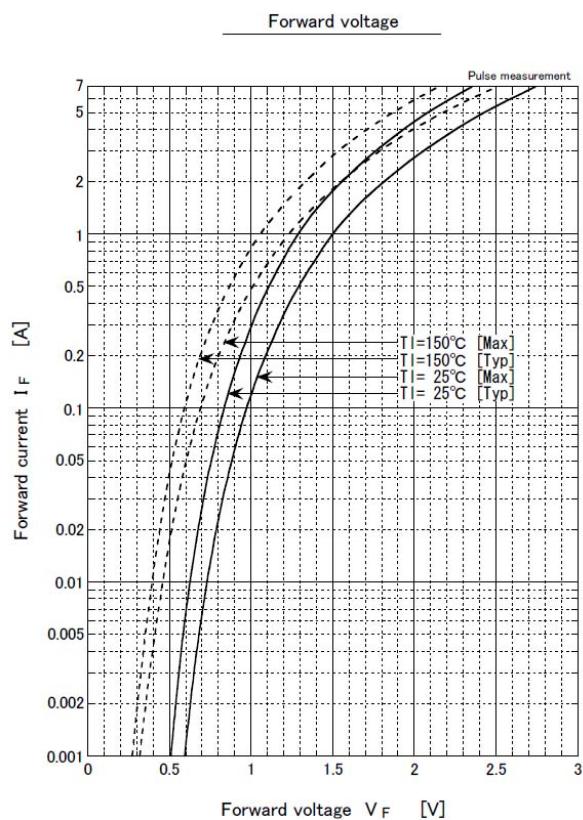
* : See the original Specifications

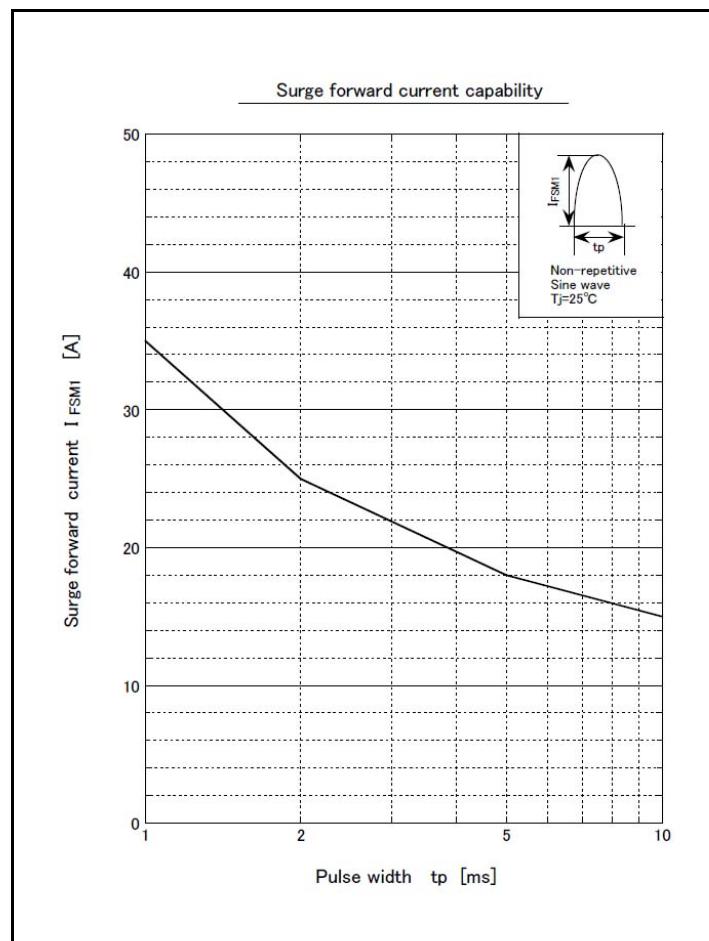
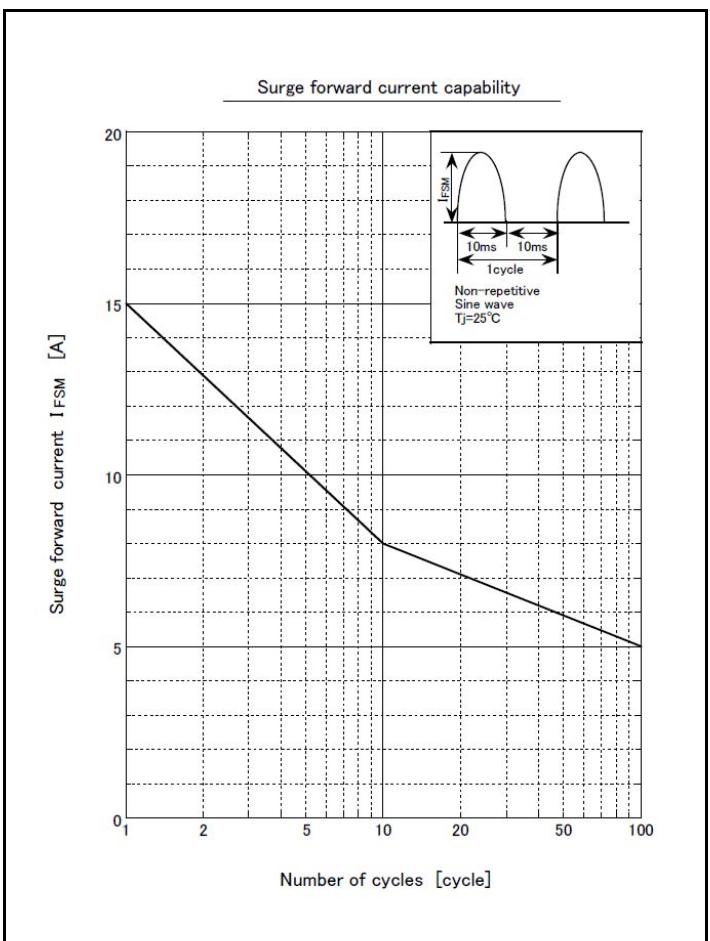
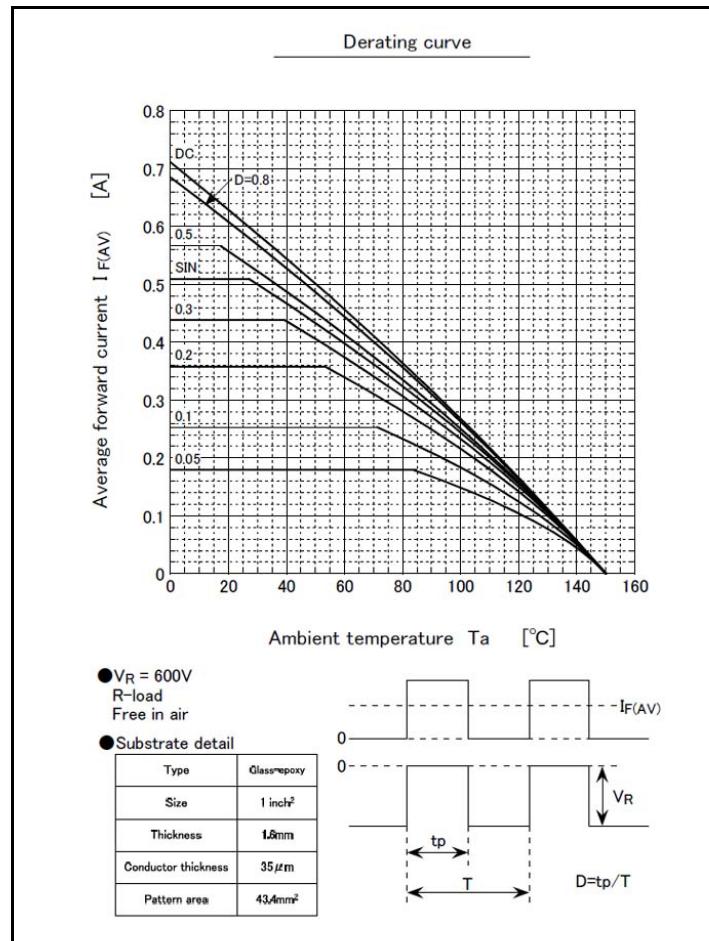
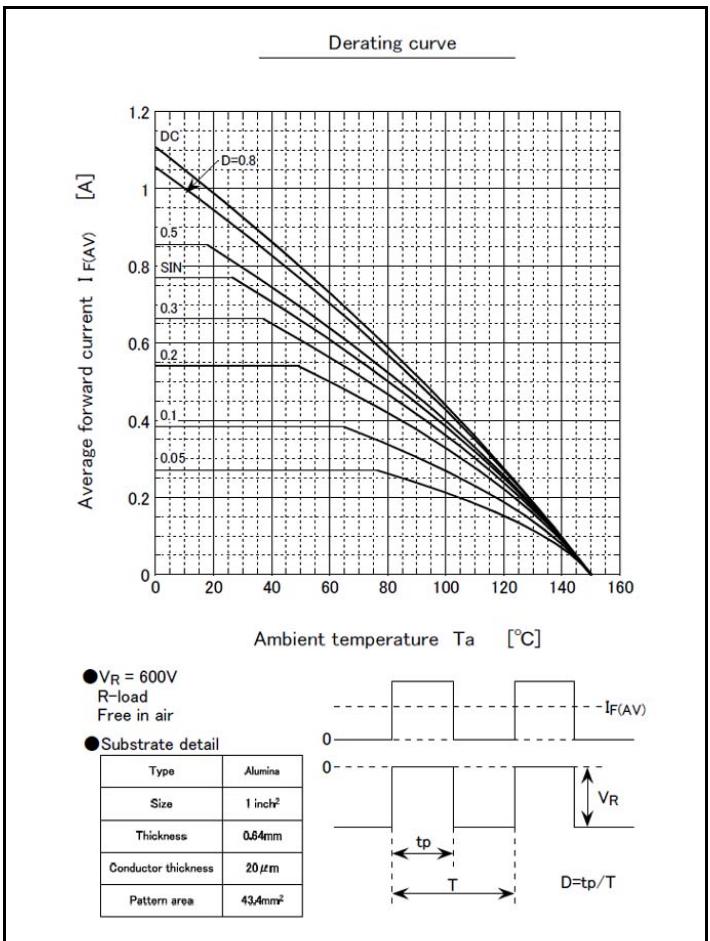
Electrical Characteristics (unless otherwise specified : T_I=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Forward voltage	V _F	IF=1A, Pulse measurement			1.5	V
Reverse current	I _R	VR=600V, Pulse measurement			10	μA
Reverse recovery time	t _{rr}	IF=0.5A, IR=1.0A, 0.25IR			75	ns
Total capacitance	C _t	f=1MHz, VR=10V		6		pF
Thermal resistance	R _{th(j-l)}	Junction to lead			20	°C/W
Thermal resistance	R _{th(j-a)}	Junction to ambient, On alumina substrate *			108	°C/W
Thermal resistance	R _{th(j-a)}	Junction to ambient, On glass-epoxy substrate *			186	°C/W

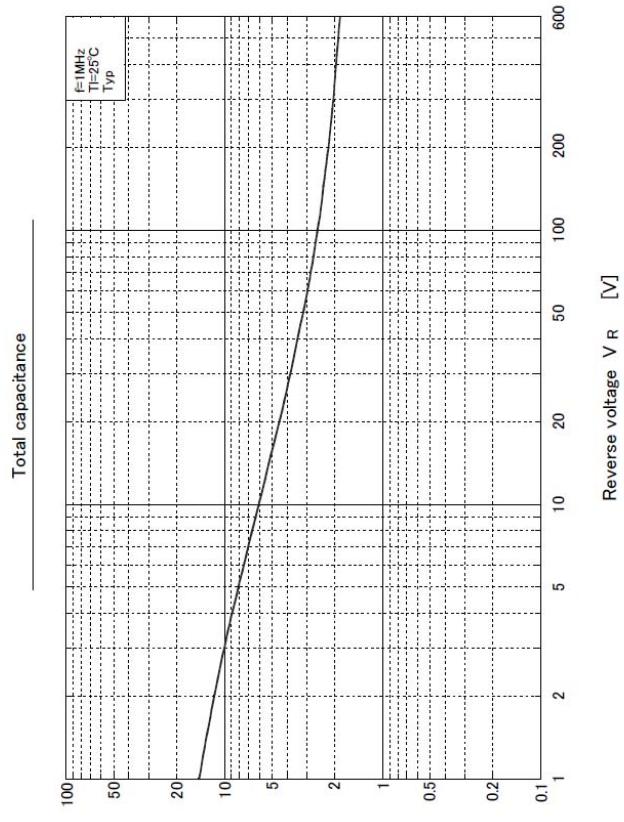
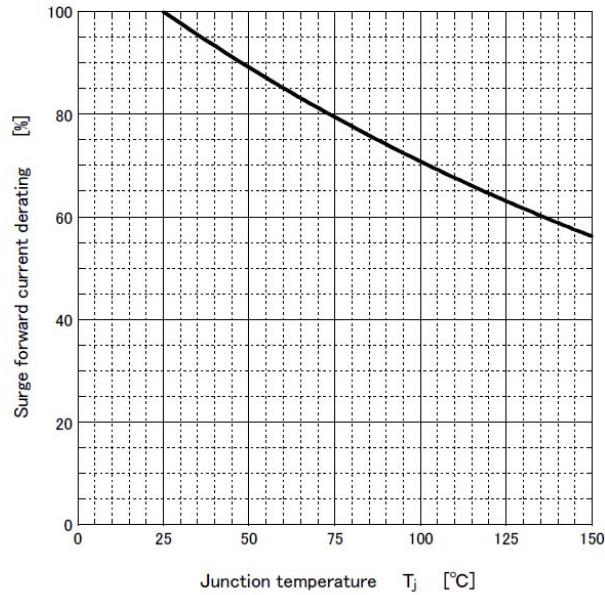
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CHARACTERISTIC DIAGRAMS

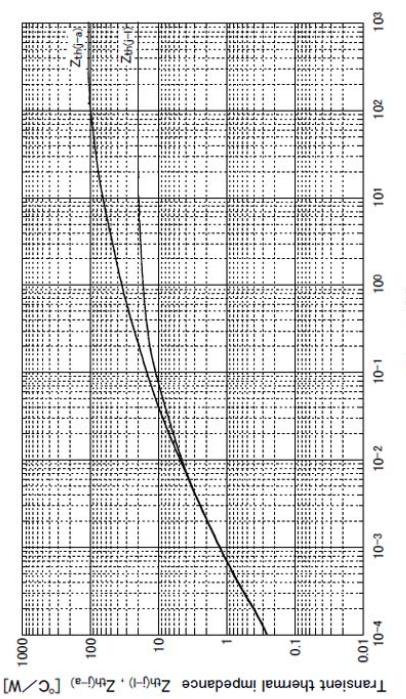




Surge forward current derating
vs Junction temperature



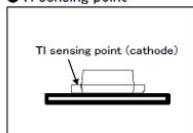
Transient thermal impedance



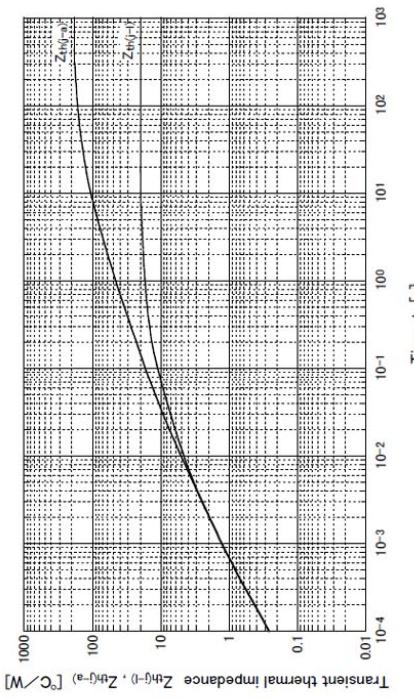
● Substrate detail

Type	Alumina
Size	1 inch ²
Thickness	0.64mm
Conductor thickness	20 μm
Pattern area	434mm ²

● TI sensing point



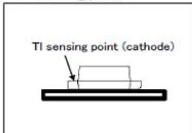
Transient thermal impedance



● Substrate detail

Type	Glass-epoxy
Size	1 inch ²
Thickness	1.6mm
Conductor thickness	35 μm
Pattern area	434mm ²

● TI sensing point



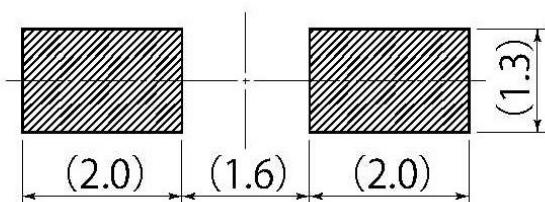
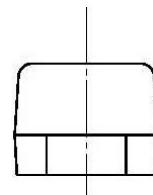
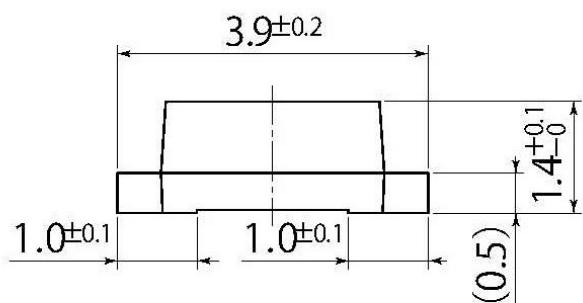
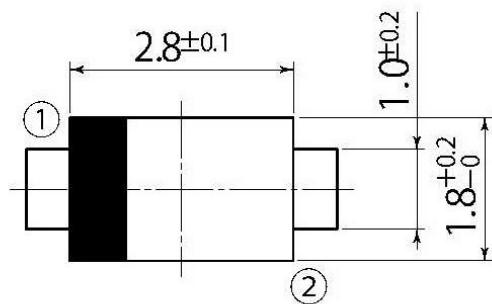
Outline Dimensions

unit:mm

scale: 10/1

B2

JEDEC Code	DO-219AA similar
JEITA Code	-
House Name	M1F



Referential Soldering Pad

- Optimize soldering pad to the board design and soldering condition.